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REVISION HISTORY

6/2019—Rev. B to Rev. C

Deleted LFCSP	Universal
Changes to Features Section and General Description Section	1
Changes to Absolute Maximum Ratings Section	6
Deleted Figure 6; Renumbered Sequentially	7
Changes to Table 6	7
Changes to Circuit Information Section	12
Changes to Table 8	15
Change to Layout Section	23
Deleted Figure 49	24
Changes to Ordering Guide	24

6/2014—Rev. A to Rev. B

Added Patent Footnote	1
Changes to Evaluating the AD7693 Performance Section	23
Updated Outline Dimensions (Dimensions Not Changed; Lead-to-Pad Dimensions Updated for JEDEC Compliance) ...	24
Changes to Ordering Guide	24

6/2011—Rev. 0 to Rev. A

Changes to Resolution Parameter and Common-Mode Input Range Parameter in Table 2	3
Changes to Figure 6 and Table 6	7
Updated Outline Dimensions	24
Changes to Ordering Guide	24

12/2006—Revision 0: Initial Version

SPECIFICATIONS

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, VREF = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 2.

Parameter	Conditions/Comments	Min	Typ	Max	Unit
RESOLUTION		16			Bits
ANALOG INPUT					
Voltage Range	IN+ – (IN–)	–V _{REF}		+V _{REF}	V
Absolute Input Voltage	IN+, IN–	–0.1		V _{REF} + 0.1	V
Common-Mode Input Range	IN+, IN–	V _{REF} /2 – 0.1	V _{REF} /2	V _{REF} /2 + 0.1	V
Analog Input CMRR	f _{IN} = 250 kHz		65		dB
Leakage Current at 25°C	Acquisition phase		1		nA
Input Impedance ¹					
THROUGHPUT					
Conversion Rate		0		500	kSPS
Transient Response	Full-scale step			400	ns
ACCURACY					
No Missing Codes		16			Bits
Integral Linearity Error		–0.5	±0.25	+0.5	LSB ²
Differential Linearity Error		–0.5	±0.25	+0.5	LSB
Transition Noise			0.35		LSB
Gain Error ³	REF = VDD = 5 V	–20	±0.5	+20	LSB
Gain Error Temperature Drift			±0.3		ppm/°C
Zero Error ³		–5	±0.5	+5	LSB
Zero Temperature Drift			±0.3		ppm/°C
Power Supply Sensitivity	VDD = 5 V ± 5%		±1		ppm
AC ACCURACY ⁴					
Dynamic Range		96	96.5		dB ⁵
Signal-to-Noise	f _{IN} = 1 kHz	95.5	96		dB
	f _{IN} = 10 kHz		95.5		dB
	f _{IN} = 100 kHz		93		dB
	f _{IN} = 1 kHz, V _{REF} = 2.5 V		93		dB
Signal-to-(Noise + Distortion)	f _{IN} = 1 kHz	95.5	96		dB
	f _{IN} = 10 kHz		95.5		dB
	f _{IN} = 100 kHz		90		dB
Total Harmonic Distortion	f _{IN} = 1 kHz		–120	–108	dB
	f _{IN} = 10 kHz		–113		dB
	f _{IN} = 100 kHz		–92		dB
Spurious-Free Dynamic Range	f _{IN} = 1 kHz		120		dB
	f _{IN} = 10 kHz		114		dB
	f _{IN} = 100 kHz		93.5		dB
Intermodulation Distortion ⁶			115		dB

¹ See the Analog Inputs section.

² LSB means least significant bit. With the ±5 V input range, one LSB is 152.6 μV.

³ See the Terminology section. These specifications include full temperature range variation but not the error contribution from the external reference.

⁴ With V_{REF} = 5 V, unless otherwise noted.

⁵ All specifications expressed in decibels are referred to a full-scale input FSR and tested with an input signal at 0.5 dB below full scale, unless otherwise specified.

⁶ f_{IN1} = 21.4 kHz and f_{IN2} = 18.9 kHz, with each tone at –7 dB below full scale.

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, V_{REF} = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 3.

Parameter	Conditions/Comments	Min	Typ	Max	Unit
REFERENCE					
Voltage Range		0.5		VDD + 0.3	V
Load Current	500 kSPS, REF = 5 V		100		μA
SAMPLING DYNAMICS					
–3 dB Input Bandwidth			9		MHz
Aperture Delay	VDD = 5V		2.5		ns
DIGITAL INPUTS					
Logic Levels					
V _{IL}		–0.3		+0.3 × VIO	V
V _{IH}		0.7 × VIO		VIO + 0.3	V
I _{IL}		–1		+1	μA
I _{IH}		–1		+1	μA
DIGITAL OUTPUTS					
Data Format	Serial 16 bits, twos complement				
Pipeline Delay ¹					
V _{OL}	I _{SINK} = +500 μA			0.4	V
V _{OH}	I _{SOURCE} = –500 μA	VIO – 0.3			V
POWER SUPPLIES					
VDD	Specified performance	4.5		5.5	V
VIO	Specified performance	2.3		VDD + 0.3	V
VIO Range		1.8		VDD + 0.3	V
Standby Current ^{2,3}	VDD and VIO = 5 V, 25°C		1	50	nA
Power Dissipation	100 SPS throughput		5		μW
	100 kSPS throughput		4		mW
	500 kSPS throughput		18	21.5	mW
Energy per Conversion			40		nJ
TEMPERATURE RANGE ⁴					
Specified Performance	T _{MIN} to T _{MAX}	–40		+85	°C

¹ Conversion results available immediately after completed conversion.

² With all digital inputs forced to VIO or GND as required.

³ During acquisition phase.

⁴ Contact an Analog Devices sales representative for the extended temperature range.

TIMING SPECIFICATIONS

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, VREF = VDD, all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 4.¹

Parameter	Symbol	Min	Typ	Max	Unit
Conversion Time: CNV Rising Edge to Data Available	t _{CONV}	0.5		1.6	μs
Acquisition Time	t _{ACQ}	400			ns
Time Between Conversions	t _{CYC}	2.0			μs
CNV Pulse Width (\overline{CS} Mode)	t _{CNVH}	10			ns
SCK Period (\overline{CS} Mode)	t _{SCK}	15			ns
SCK Period (Chain Mode)	t _{SCK}				
VIO Above 4.5 V		17			ns
VIO Above 3 V		18			ns
VIO Above 2.7 V		19			ns
VIO Above 2.3 V		20			ns
SCK Low Time	t _{SCKL}	7			ns
SCK High Time	t _{SCKH}	7			ns
SCK Falling Edge to Data Remains Valid	t _{HSDO}	4			ns
SCK Falling Edge to Data Valid Delay	t _{DSDO}				
VIO Above 4.5 V				14	ns
VIO Above 3 V				15	ns
VIO Above 2.7 V				16	ns
VIO Above 2.3 V				17	ns
CNV or SDI Low to SDO D15 MSB Valid (\overline{CS} Mode)	t _{EN}				
VIO Above 4.5 V				15	ns
VIO Above 2.7 V				18	ns
VIO Above 2.3 V				22	ns
CNV or SDI High or Last SCK Falling Edge to SDO High Impedance (\overline{CS} Mode)	t _{DIS}			25	ns
SDI Valid Setup Time from CNV Rising Edge (\overline{CS} Mode)	t _{SSDICNV}	15			ns
SDI Valid Hold Time from CNV Rising Edge (\overline{CS} Mode)	t _{HSDICNV}	0			ns
SCK Valid Setup Time from CNV Rising Edge (Chain Mode)	t _{SSCKCNV}	5			ns
SCK Valid Hold Time from CNV Rising Edge (Chain Mode)	t _{HSCKCNV}	10			ns
SDI Valid Setup Time from SCK Falling Edge (Chain Mode)	t _{SSDISCK}	4			ns
SDI Valid Hold Time from SCK Falling Edge (Chain Mode)	t _{HSDISCK}	4			ns
SDI High to SDO High (Chain Mode with Busy Indicator)	t _{DSDOSDI}				
VIO Above 4.5 V				15	ns
VIO Above 2.3 V				26	ns

¹ See Figure 3 and Figure 4 for load conditions.

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Analog Inputs IN+, ¹ IN– ¹	GND – 0.3 V to VDD + 0.3 V or ±130 mA
REF	GND – 0.3 V to VDD + 0.3 V
Supply Voltages	
VDD, VIO to GND	–0.3 V to +7 V
VDD to VIO	±7 V
Digital Inputs to GND	–0.3 V to VIO + 0.3 V
Digital Outputs to GND	–0.3 V to VIO + 0.3 V
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
θ_{JA} Thermal Impedance	200°C/W
θ_{JC} Thermal Impedance	44°C/W
Lead Temperature Range	JEDEC J-STD-20

¹ See the Analog Inputs section.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

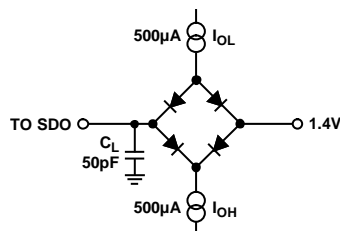


Figure 3. Load Circuit for Digital Interface Timing

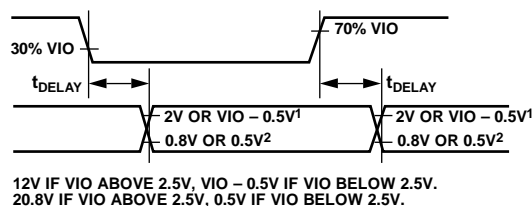


Figure 4. Voltage Levels for Timing

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

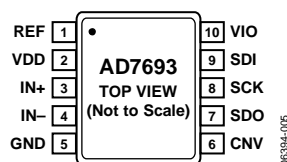


Figure 5. Pin Configuration

Table 6. Pin Function Descriptions

Pin No.	Mnemonic	Type ¹	Description
1	REF	AI	Reference Input Voltage. The REF range is from 0.5 V to VDD. It is referred to the GND pin. This pin should be decoupled closely to the pin with a 10 μ F capacitor.
2	VDD	P	Power Supply.
3	IN+	AI	Differential Positive Analog Input.
4	IN-	AI	Differential Negative Analog Input.
5	GND	P	Power Supply Ground.
6	CNV	DI	Convert Input. This input has multiple functions. On its leading edge, it initiates the conversions and selects the interface mode of the part: chain or \overline{CS} mode. In chain mode, the data should be read when CNV is high. In \overline{CS} mode, the SDO pin is enabled when CNV is low.
7	SDO	DO	Serial Data Output. The conversion result is output on this pin. It is synchronized to SCK.
8	SCK	DI	Serial Data Clock Input. When the part is selected, the conversion result is shifted out by this clock.
9	SDI	DI	Serial Data Input. This input provides multiple features. It selects the interface mode of the ADC as follows: Chain mode is selected if SDI is low during the CNV rising edge. In this mode, SDI is used as a data input to daisy-chain the conversion results of two or more ADCs onto a single SDO line. The digital data level on SDI is output on SDO with a delay of 16 SCK cycles. \overline{CS} mode is selected if SDI is high during the CNV rising edge. In this mode, either SDI or CNV can enable the serial output signals when low and if SDI or CNV is low when the conversion is complete, the busy indicator feature is enabled.
10	VIO	P	Input/Output Interface Digital Power. Nominally at the same supply as the host interface (1.8 V, 2.5 V, 3 V, or 5 V).

¹AI = analog input, DI = digital input, DO = digital output, and P = power.

TERMINOLOGY

Least Significant Bit (LSB)

The LSB is the smallest increment that can be represented by a converter. For a differential analog-to-digital converter with N bits of resolution, the LSB expressed in volts is

$$LSB (V) = \frac{2V_{REF}}{2^N}$$

Integral Nonlinearity Error (INL)

INL refers to the deviation of each individual code from a line drawn from negative full scale through positive full scale. The point used as negative full scale occurs $\frac{1}{2}$ LSB before the first code transition. Positive full scale is defined as a level $1\frac{1}{2}$ LSB beyond the last code transition. The deviation is measured from the middle of each code to the true straight line (see Figure 25).

Differential Nonlinearity Error (DNL)

In an ideal ADC, code transitions are 1 LSB apart. DNL is the maximum deviation from this ideal value. It is often specified in terms of resolution for which no missing codes are guaranteed.

Zero Error

Zero error is the difference between the ideal midscale voltage, that is, 0 V, from the actual voltage producing the midscale output code, that is, 0 LSB.

Gain Error

The first transition (from 100 ... 00 to 100 ... 01) should occur at a level $\frac{1}{2}$ LSB above nominal negative full scale (-4.999847 V for the ± 5 V range). The last transition (from 011 ... 10 to 011 ... 11) should occur for an analog voltage $1\frac{1}{2}$ LSB below the nominal full scale ($+4.999771$ V for the ± 5 V range.) The gain error is the deviation of the difference between the actual level of the last transition and the actual level of the first transition from the difference between the ideal levels.

Aperture Delay

Aperture delay is the measure of the acquisition performance. It is the time between the rising edge of the CNV input and when the input signal is held for a conversion.

Transient Response

Transient response is the time required for the ADC to accurately acquire its input after a full-scale step function is applied.

Dynamic Range

Dynamic range is the ratio of the rms value of the full scale to the total rms noise measured with the inputs shorted together. The value for dynamic range is expressed in decibels.

Signal-to-Noise Ratio (SNR)

SNR is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, excluding harmonics and dc. The value for SNR is expressed in decibels.

Signal-to-(Noise + Distortion) Ratio (SINAD)

SINAD is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for SINAD is expressed in decibels.

Total Harmonic Distortion (THD)

THD is the ratio of the rms sum of the first five harmonic components to the rms value of a full-scale input signal and is expressed in decibels.

Spurious-Free Dynamic Range (SFDR)

SFDR is the difference, in decibels, between the rms amplitude of the input signal and the peak spurious signal.

Effective Number of Bits (ENOB)

ENOB is a measurement of the resolution with a sine wave input. It is related to SINAD by the following formula:

$$ENOB = (SINAD_{dB} - 1.76)/6.02$$

and is expressed in bits.

TYPICAL PERFORMANCE CHARACTERISTICS

VDD = 4.5 V to 5.5 V, VIO = 2.3 V to VDD, VREF = VDD, TA = 25°C.

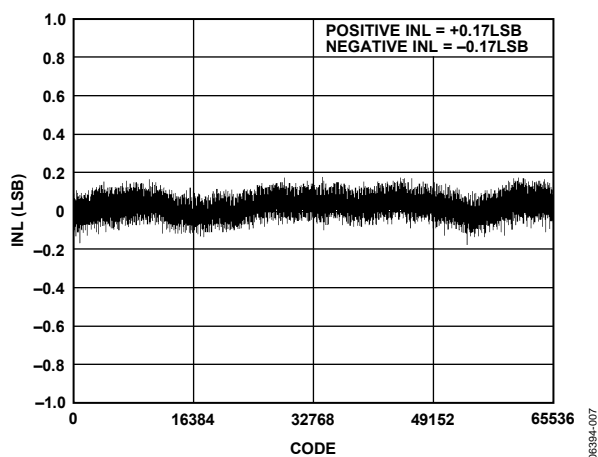


Figure 6. Integral Nonlinearity vs. Code

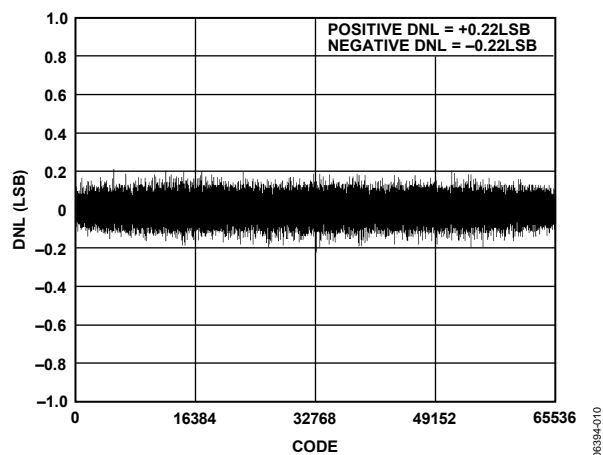


Figure 9. Differential Nonlinearity vs. Code

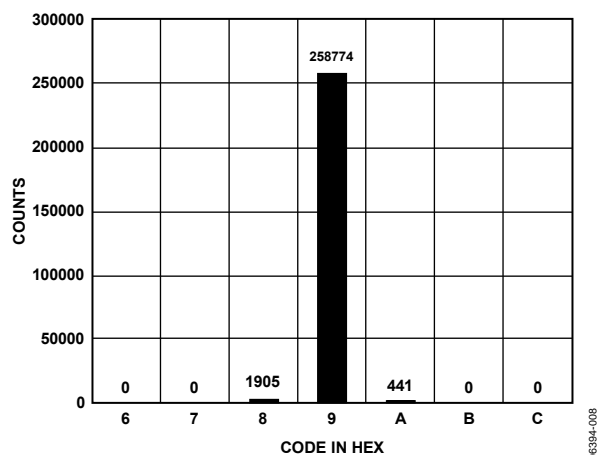


Figure 7. Histogram of a DC Input at the Code Center

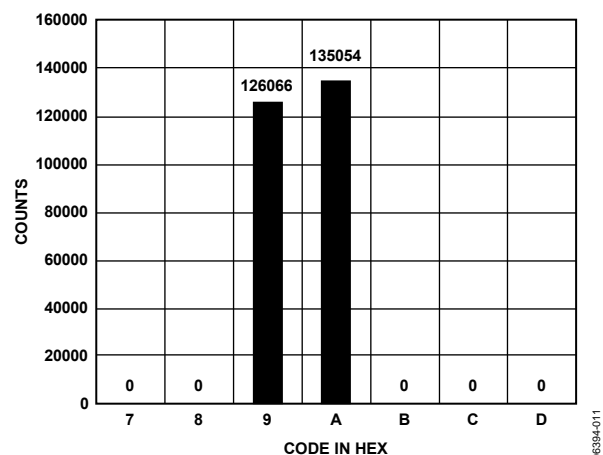


Figure 10. Histogram of a DC Input at the Code Transition

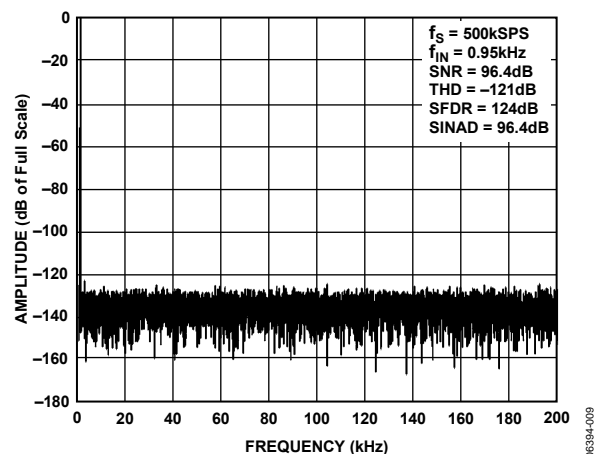


Figure 8. FFT Plot

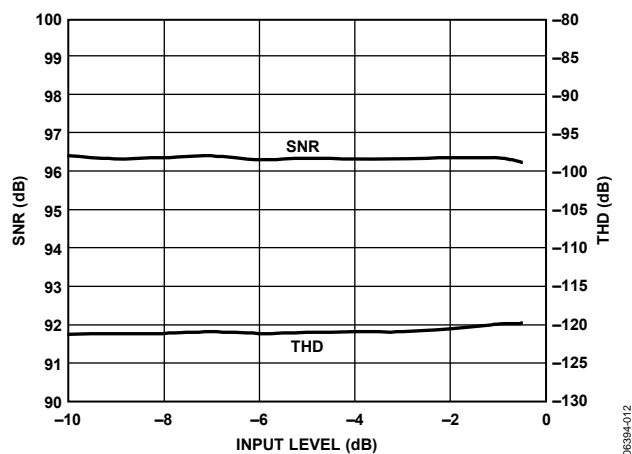


Figure 11. SNR, THD vs. Input Level

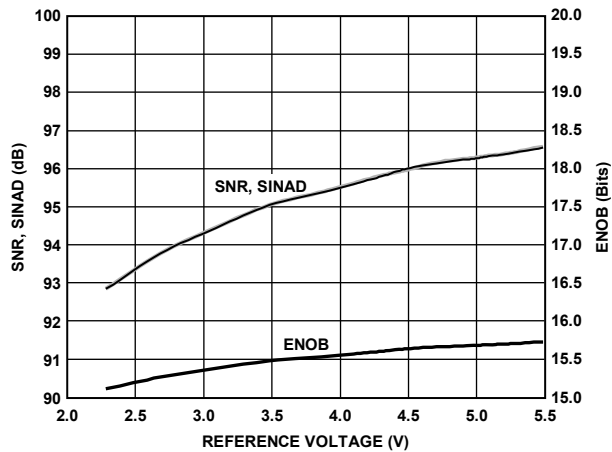


Figure 12. SNR, SINAD, and ENOB vs. Reference Voltage

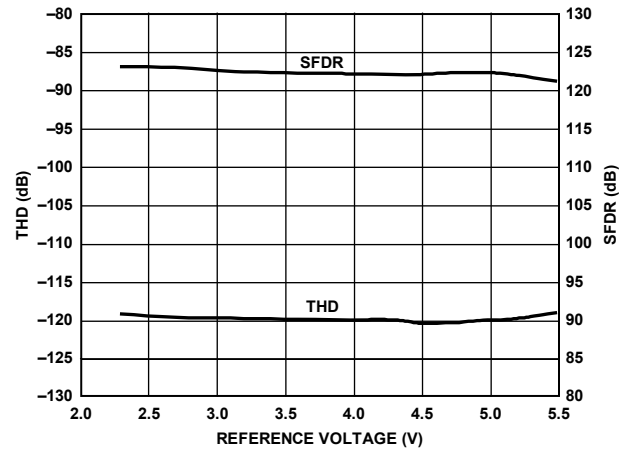


Figure 15. THD, SFDR vs. Reference Voltage

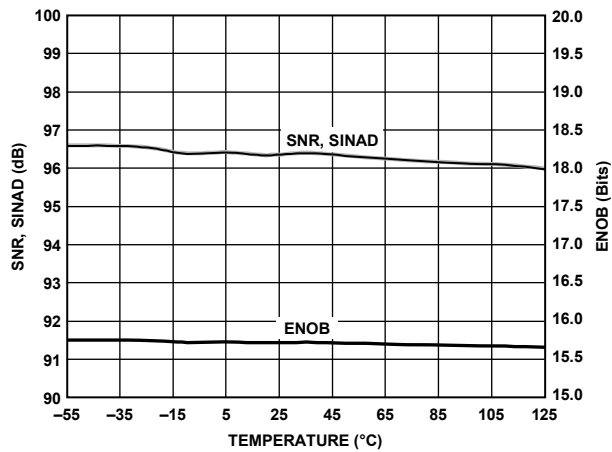


Figure 13. SNR, SINAD, and ENOB vs. Temperature

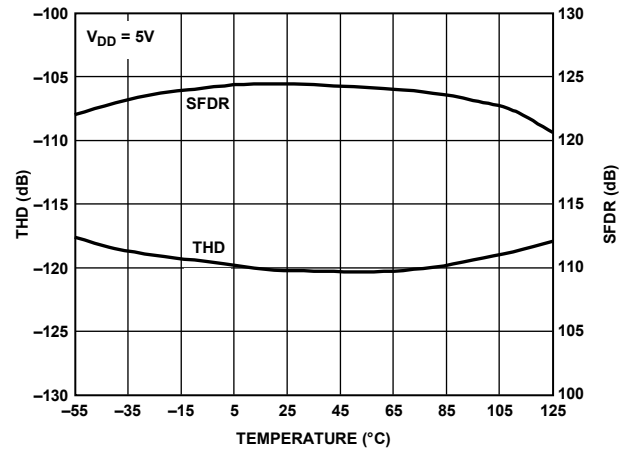


Figure 16. THD, SFDR vs. Temperature

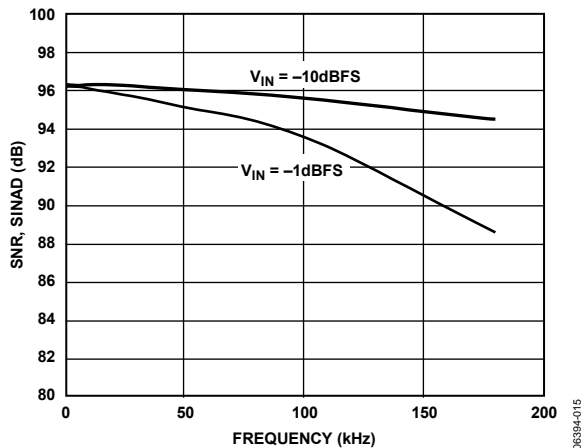


Figure 14. SINAD vs. Frequency

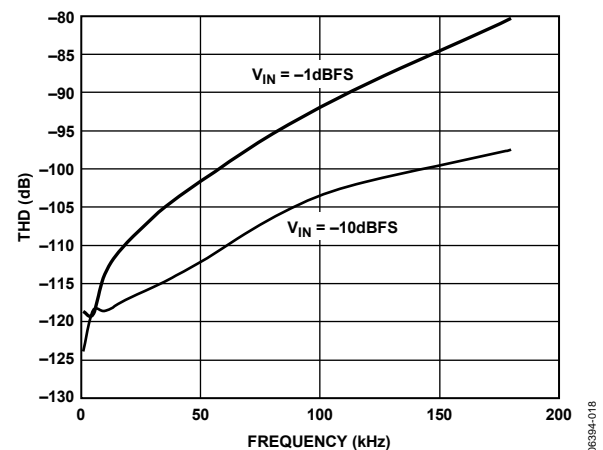


Figure 17. THD vs. Frequency

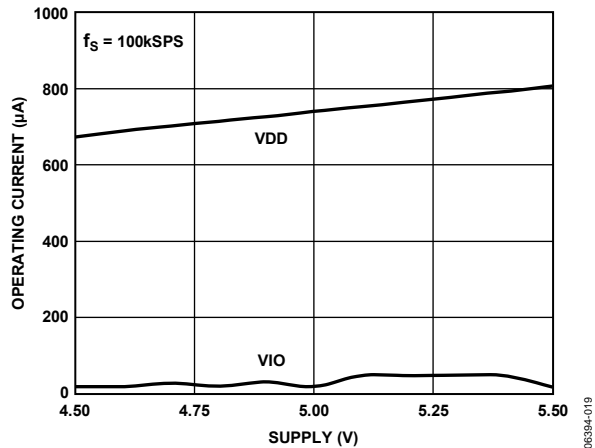


Figure 18. Operating Currents vs. Supply

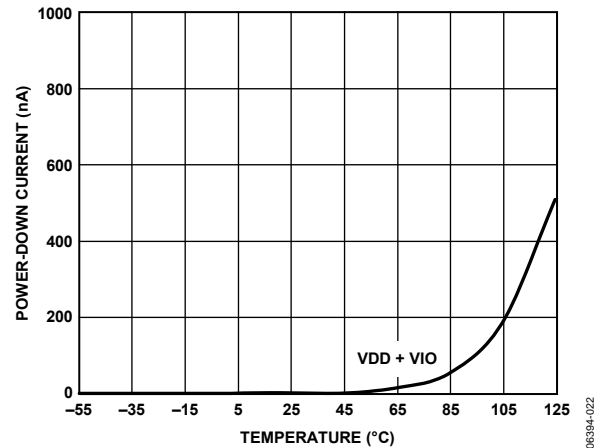


Figure 21. Power-Down Currents vs. Temperature

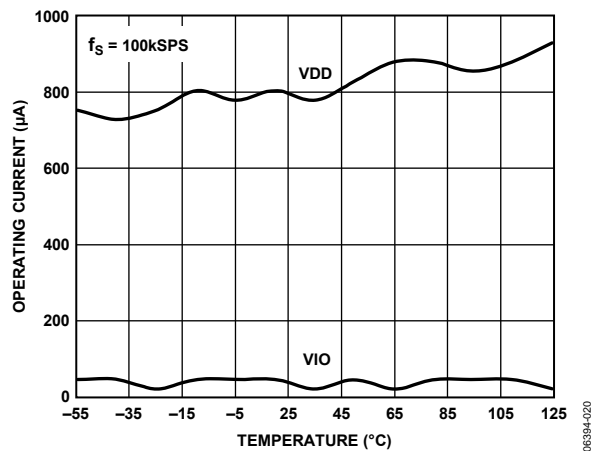


Figure 19. Operating Currents vs. Temperature

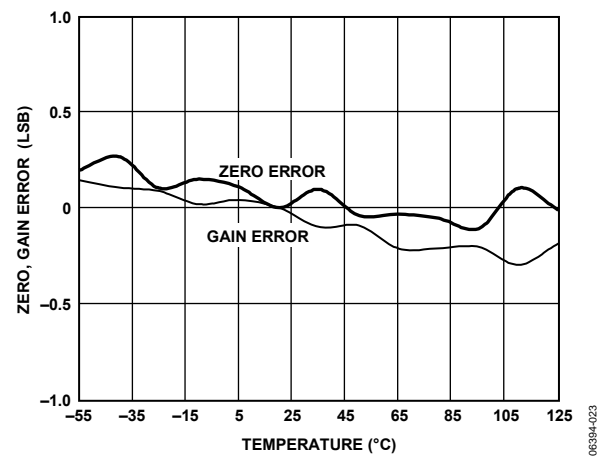


Figure 22. Zero Error and Gain Error vs. Temperature

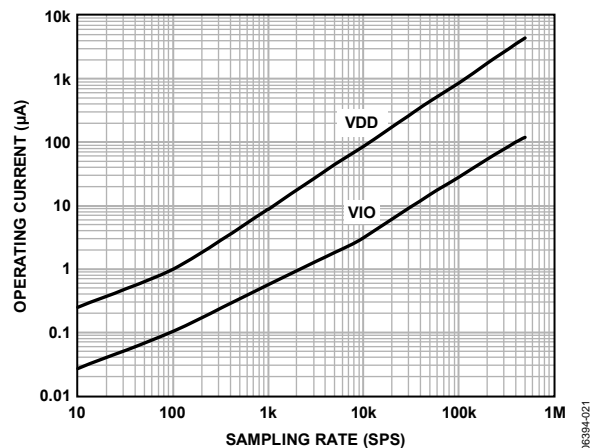
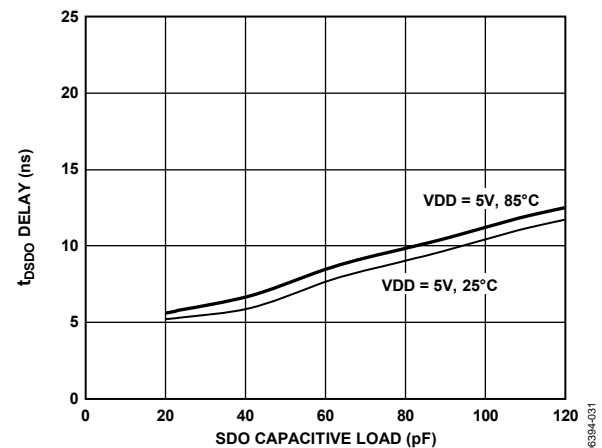


Figure 20. Operating Currents vs. Sample Rate

Figure 23. t_{DSO} Delay vs. Capacitance Load and Supply

THEORY OF OPERATION

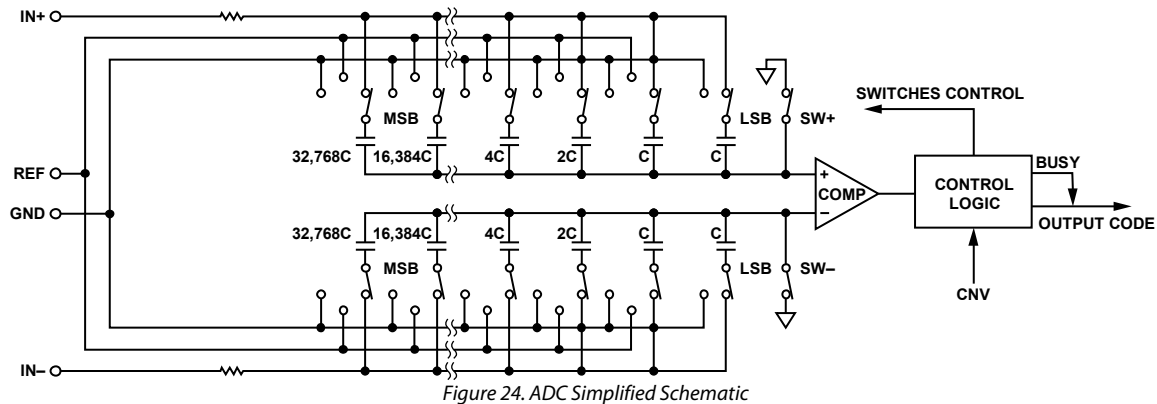


Figure 24. ADC Simplified Schematic

CIRCUIT INFORMATION

The [AD7693](#) is a fast, low power, single-supply, precise, 16-bit ADC using a successive approximation architecture.

The [AD7693](#) is capable of converting 500,000 samples per second (500 kSPS) and powers down between conversions. When operating at 1 kSPS, for example, it consumes 40 μ W typically, ideal for battery-powered applications.

The [AD7693](#) provides the user with an on-chip track-and-hold and does not exhibit pipeline delay or latency, making it ideal for multiple multiplexed channel applications.

The [AD7693](#) is specified from 4.5 V to 5.5 V and can be interfaced to any 1.8 V to 5 V digital logic family. It is housed in a 10-lead MSOP.

It is pin-for-pin compatible with the 16-bit [AD7687](#) and [AD7688](#) and with the 18-bit [AD7690](#) and [AD7691](#).

CONVERTER OPERATION

The [AD7693](#) is a successive approximation ADC based on a charge redistribution DAC. Figure 24 shows the simplified schematic of the ADC. The capacitive DAC consists of two identical arrays of 16 binary-weighted capacitors, which are connected to the two comparator inputs.

During the acquisition phase, terminals of the array tied to the comparator's input are connected to GND via SW+ and SW-. All independent switches are connected to the analog inputs.

Thus, the capacitor arrays are used as sampling capacitors and acquire the analog signal on the IN+ and IN- inputs. When the acquisition phase is complete and the CNV input goes high, a conversion phase is initiated. When the conversion phase begins, SW+ and SW- are opened first. The two capacitor arrays are then disconnected from the inputs and connected to the GND input. Therefore, the differential voltage between the IN+ and IN- inputs captured at the end of the acquisition phase is applied to the comparator inputs, causing the comparator to become unbalanced. By switching each element of the capacitor array between GND and REF, the comparator input varies by binary-weighted voltage steps ($V_{REF}/2$, $V_{REF}/4$... $V_{REF}/32,768$). The control logic toggles these switches, starting with the MSB, to bring the comparator back into a balanced condition. After the completion of this process, the part returns to the acquisition phase, and the control logic generates the ADC output code and a busy signal indicator.

Because the [AD7693](#) has an on-board conversion clock, the serial clock, SCK, is not required for the conversion process.

Transfer Functions

The ideal transfer characteristic for the AD7693 is shown in Figure 25 and Table 7.

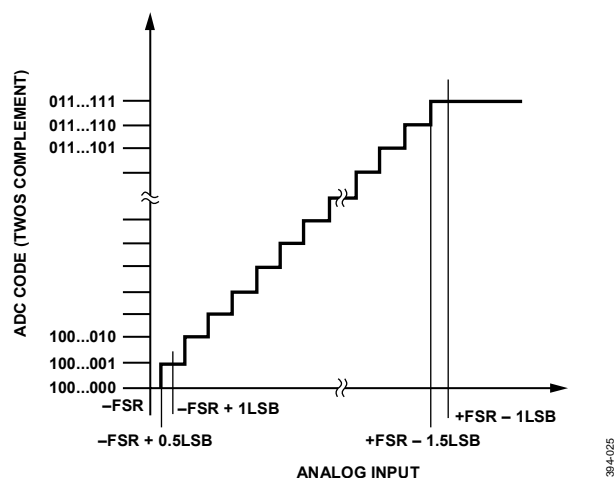


Figure 25. ADC Ideal Transfer Function

Table 7. Output Codes and Ideal Input Voltages

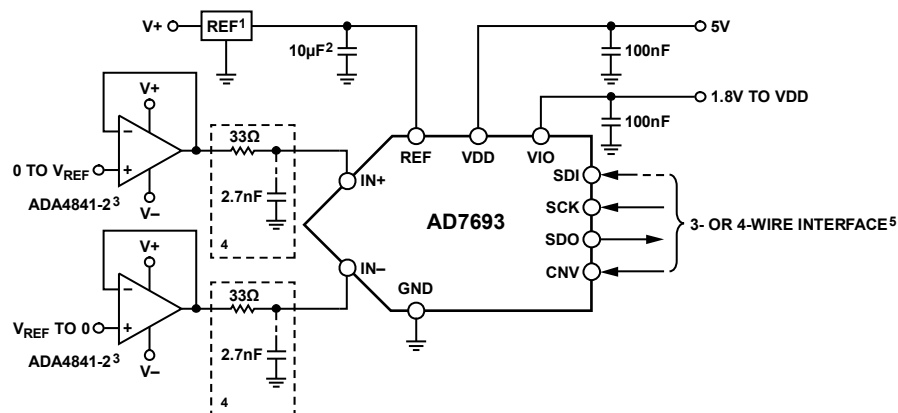
Description	Analog Input $V_{REF} = 5\text{ V}$	Digital Output Code (Hex)
FSR - 1 LSB	+4.999847 V	0x7FFF ¹
Midscale + 1 LSB	+152.6 μV	0x0001
Midscale	0 V	0x0000
Midscale - 1 LSB	-152.6 μV	0xFFFF
-FSR + 1 LSB	-4.999847 V	0x8001
-FSR	-5 V	0x8000 ²

¹ This is also the code for an overranged analog input ($V_{IN+} - V_{IN-}$ above $V_{REF} - V_{GND}$).

² This is also the code for an underranged analog input ($V_{IN+} - V_{IN-}$ below V_{GND}).

TYPICAL CONNECTION DIAGRAM

Figure 26 shows an example of the recommended connection diagram for the AD7693 when multiple supplies are available.



¹SEE REFERENCE SECTION FOR REFERENCE SELECTION.

² C_{REF} IS USUALLY A 10 μF CERAMIC CAPACITOR (X5R).

³SEE TABLE 8 FOR ADDITIONAL RECOMMENDED AMPLIFIERS.

⁴OPTIONAL FILTER. SEE ANALOG INPUT SECTION.

⁵SEE THE DIGITAL INTERFACE SECTION FOR MOST CONVENIENT INTERFACE MODE.

Figure 26. Typical Application Diagram with Multiple Supplies

ANALOG INPUTS

Figure 27 shows an equivalent circuit of the input structure of the AD7693.

The two diodes, D1 and D2, provide ESD protection for the analog inputs, IN+ and IN-. Care must be taken to ensure that the analog input signal does not exceed the supply rails by more than 0.3 V because this causes the diodes to become forward biased and to start conducting current. These diodes can handle a forward-biased current of 130 mA maximum. For instance, these conditions could eventually occur when the input buffer's (U1) supplies are different from VDD. In such a case, for example, an input buffer with a short circuit, the current limitation can be used to protect the part.

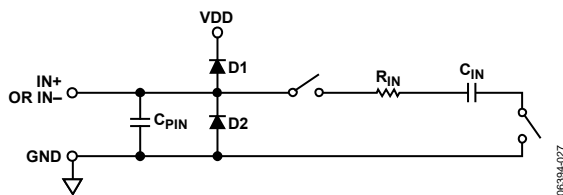


Figure 27. Equivalent Analog Input Circuit

The analog input structure allows the sampling of the true differential signal between IN+ and IN-. By using these differential inputs, signals common to both inputs are rejected.

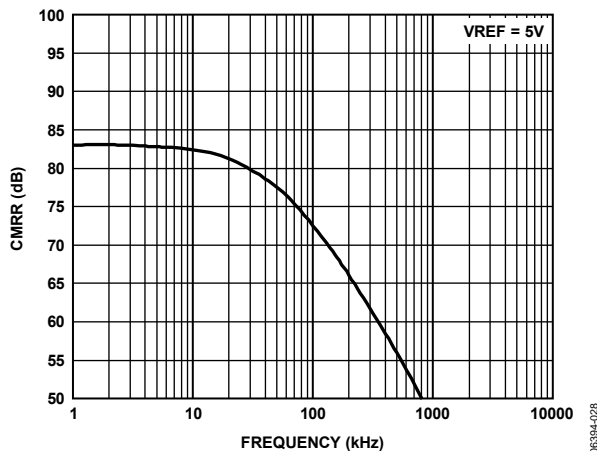


Figure 28. Analog Input CMRR vs. Frequency

During the acquisition phase, the impedance of the analog inputs (IN+ and IN-) can be modeled as a parallel combination of the capacitor, C_{PIN} , and the network formed by the series connection of R_{IN} and C_{IN} . C_{PIN} is primarily the pin capacitance. R_{IN} is typically 600 Ω and is a lumped component made up of serial resistors and the on resistance of the switches. C_{IN} is typically 30 pF and is mainly the ADC sampling capacitor.

During the conversion phase, where the switches are opened, the input impedance is limited to C_{PIN} . R_{IN} and C_{IN} make a 1-pole, low-pass filter that reduces undesirable aliasing effects and limits the noise.

When the source impedance of the driving circuit is low, the AD7693 can be driven directly. Large source impedances significantly affect the ac performance, especially total

harmonic distortion (THD). The dc performances are less sensitive to the input impedance. The maximum source impedance depends on the amount of THD that can be tolerated. The THD degrades as a function of the source impedance and the maximum input frequency.

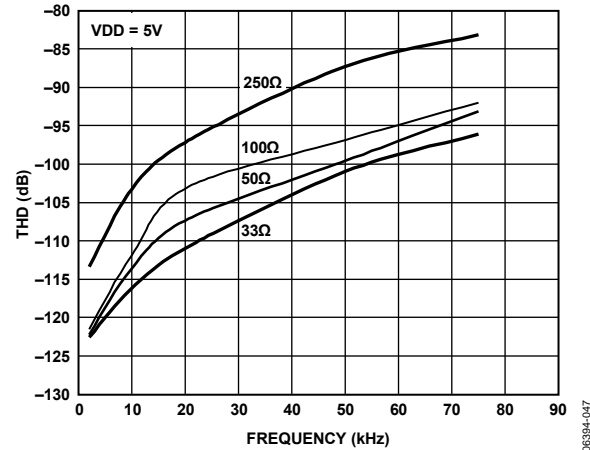


Figure 29. THD vs. Analog Input Frequency and Source Resistance

DRIVER AMPLIFIER CHOICE

Although the AD7693 is easy to drive, the driver amplifier must meet the following requirements:

- The noise generated by the driver amplifier needs to be kept as low as possible to preserve the SNR and transition noise performance of the AD7693. The noise coming from the driver is filtered by the AD7693 analog input circuit's 1-pole, low-pass filter made by R_{IN} and C_{IN} or by the external filter, if one is used. Because the typical noise of the AD7693 is 56 $\mu\text{V rms}$, the SNR degradation due to the amplifier is

$$SNR_{LOSS} = 20 \log \left(\frac{56}{\sqrt{56^2 + \frac{\pi}{2} f_{-3dB} (Ne_N)^2 + \frac{\pi}{2} f_{-3dB} (Ne_N)^2}} \right)$$

where:

f_{-3dB} is the input bandwidth in megahertz of the AD7693 (9 MHz) or the cutoff frequency of the input filter, if one is used.

N is the noise gain of the amplifier (for example, 1 in buffer configuration).

e_N is the equivalent input noise voltage of the op amp, in nV/ $\sqrt{\text{Hz}}$.

- For ac applications, the driver should have a THD performance commensurate with the AD7693.
- For multichannel multiplexed applications, the driver amplifier and the AD7693 analog input circuit must settle for a full-scale step onto the capacitor array at a 16-bit level (0.0015%, 15 ppm). In the amplifier's data sheet, settling at 0.1% to 0.01% is more commonly specified. This could differ significantly from the settling time at a 16-bit level and should be verified prior to driver selection.

Table 8. Recommended Driver Amplifiers

Amplifier	Typical Application
ADA4941-1	Very low noise, low power single to differential
ADA4841-1, ADA4841-2	Very low noise, small, and low power
AD8655	5 V single supply, low noise
AD8021	Very low noise and high frequency
AD8022	Low noise and high frequency
OP184	Low power, low noise, and low frequency
AD8605, AD8615	5 V single supply, low power

SINGLE-ENDED-TO-DIFFERENTIAL DRIVER

For applications using a single-ended analog signal, either bipolar or unipolar, the [ADA4941-1](#) single-ended-to-differential driver allows for a differential input into the part. The schematic is shown in Figure 30.

R1 and R2 set the attenuation ratio between the input range and the ADC range (V_{REF}). R1, R2, and C_F are chosen depending on the desired input resistance, signal bandwidth, antialiasing and noise contribution. For example, for the ± 10 V range with a 4 k Ω impedance, R2 = 1 k Ω and R1 = 4 k Ω .

R3 and R4 set the common mode on the IN $-$ input, and R5 and R6 set the common mode on the IN $+$ input of the ADC. The common mode should be set close to $V_{REF}/2$; however, if single supply is desired, it can be set slightly above $V_{REF}/2$ to provide some headroom for the [ADA4941-1](#) output stage. For example, for the ± 10 V range with a single supply, R3 = 8.45 k Ω , R4 = 11.8 k Ω , R5 = 10.5 k Ω , and R6 = 9.76 k Ω .

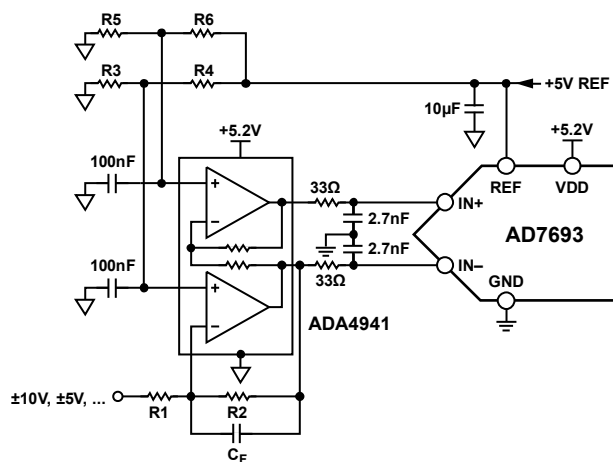


Figure 30. Single-Ended-to-Differential Driver Circuit

VOLTAGE REFERENCE INPUT

The [AD7693](#) voltage reference input, REF, has a dynamic input impedance and should therefore be driven by a low impedance source with efficient decoupling between the REF and GND pins, as explained in the Layout section.

When REF is driven by a very low impedance source (for example, a reference buffer using the [AD8031](#) or the [AD8605](#)), a 10 μ F (X5R, 0805 size) ceramic chip capacitor is appropriate for optimum performance.

If an unbuffered reference voltage is used, the decoupling value depends on the reference used. For instance, a 22 μ F (X5R, 1206 size) ceramic chip capacitor is appropriate for optimum performance using low temperature drift products such as the [ADR435](#) and [ADR445](#) references.

If desired, smaller reference decoupling capacitor values down to 2.2 μ F can be used with a minimal impact on performance, especially DNL.

Regardless, there is no need for an additional lower value ceramic decoupling capacitor (for example, 100 nF) between the REF and GND pins.

POWER SUPPLY

The [AD7693](#) uses two power supply pins: a core supply, VDD, and a digital input/output interface supply, VIO. VIO allows direct interface with any logic between 1.8 V and VDD. To reduce the supplies needed, the VIO and VDD pins can be tied together. The [AD7693](#) is independent of power supply sequencing between VIO and VDD. Additionally, it is very insensitive to power supply variations over a wide frequency range, as shown in Figure 31.

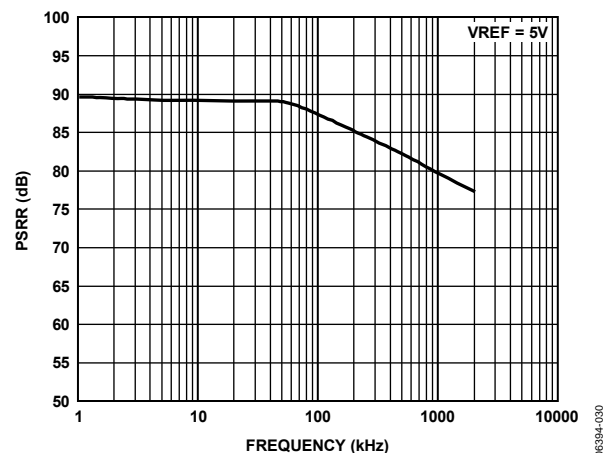


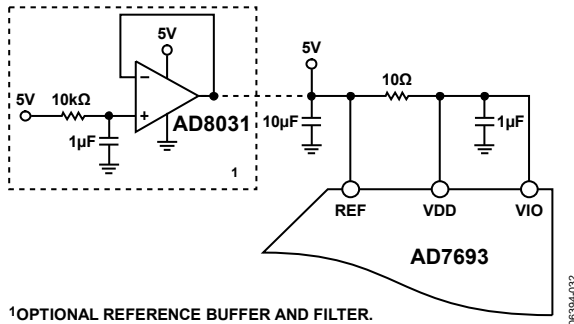
Figure 31. PSRR vs. Frequency

The [AD7693](#) powers down automatically at the end of each conversion phase; therefore, the operating currents and power scale linearly with the sampling rate (refer to Figure 20). This makes the part ideal for low sampling rates (even of a few hertz) and low battery-powered applications.

SUPPLYING THE ADC FROM THE REFERENCE

For simplified applications, the AD7693, with its low operating current, can be supplied directly using the reference circuit shown in Figure 32. The reference line can be driven by

- The system power supply directly
- A reference voltage with enough current output capability, such as the ADR435.
- A reference buffer, such as the AD8031, which can also filter the system power supply, as shown in Figure 32.



1 OPTIONAL REFERENCE BUFFER AND FILTER.

Figure 32. Example of an Application Circuit

DIGITAL INTERFACE

Generally, a user is interested in either minimizing the wiring complexity of a multichannel ADC system or communicating with the parts via a specific interface standard. Although the ADC has only four digital pins (CNV, SCK, SDI, and SDO), it offers a significantly flexible serial interface, including compatibility with SPI, QSPI, digital hosts, and DSPs (such as Blackfin® ADSP-BF537 or ADSP-2191M). By configuring the ADC into one of six modes, virtually any serial interface scenario can be accommodated.

For wiring efficiency, the best way to configure a multichannel, simultaneous-sampling system is to use the 3-wire chain mode. This system is easily created by cascading multiple (M) ADCs into a shift register structure. The CNV and CLK pins are common to all ADCs, and the SDO of one part feeds the SDI of the next part in the chain. The 3-wire interface is simply the CNV, SCK, and SDO of the last ADC in the chain. For a system containing M- and N-bit converters, the user needs to provide $M \times N$ SCK transitions to read back all of the data. This 3-wire interface is also ideally suited for isolated applications.

Additional flexibility is provided by optionally configuring the ADCs to provide a busy indication. Without a busy indication, the user must externally timeout the maximum ADC conversion time before commencing readback. This configuration is described in the Chain Mode Without Busy Indicator section. With the busy indication enabled, external timer circuits are not required because the SDO at the end of the chain provides a low-to-high transition (that is, a start bit) when all of the chain members have completed their conversions and are ready to transmit data. However, one additional SCK is required to flush the SDO busy

indication prior to reading back the data. This configuration is described in the Chain Mode with Busy Indicator section.

The primary limitations of 3-wire chain mode are that all ADCs are simultaneously sampled and the user cannot randomly select an individual ADC for readback. This can be overcome only by increasing the number of wires (for example, one chip select wire per ADC). To operate with this increased functionality, the part must be used in CS Mode. CS mode is separated into two categories (3-wire and 4-wire) whereby flexibility is traded off for wiring complexity. In CS 4-wire mode, the user has independent control over the sampling operation (via CNV) and the chip select operation (via SDI) for each ADC. In CS 3-wire mode, SDI is unused (tied high) and CNV is used to both sample the input and chip select the part when needed. As with chain mode, the parts can optionally be configured to provide a busy indication, but at the expense of one additional SCK when reading back the data. So in total there are four CS modes: 3-wire and 4-wire modes, each with busy and without busy.

There is no elaborate writing of configuration words into the part via the SDI pin. The mode in which the part operates is defined by ensuring a specific relationship between the CNV, SDI, and SCK inputs at key times. To select CS mode, ensure that SDI is high at the rising edge of CNV; otherwise, chain mode will be selected. Once in CS mode, selecting the part for readback *before* the conversion is complete (by bringing either SDI or CNV low) instructs the part to provide a busy indicator, a high-to-low impedance transition on SDO, to tell the user when the conversion has finished. If the part is selected *after* the conversion has finished, SDO outputs the MSB when it is selected. In chain mode, the busy indicator, a low-to-high transition on SDO, is selected based on the state of SCK at the rising edge of CNV. If SCK is high, the busy indicator is enabled; otherwise, the busy indicator is not enabled.

The following sections provide specifics for each of the different serial interface modes. Note that in the following sections, the timing diagrams indicate digital activity (SCK, CNV) during conversion. However, due to the possibility of performance degradation, digital activity should only occur during the first quarter of the conversion phase because the AD7693 provides error correction circuitry that can correct for an incorrect bit during this time. The user should initiate the busy indicator if desired during this time. It is also possible to corrupt the sample by having SCK or SDI transitions near the sampling instant. Therefore, it is recommended to keep the digital pins quiet for approximately 30 ns before and 10 ns after the rising edge of CNV. The exception is when the device is in the chain mode with busy configuration, where SDI is tied to CNV, because this scenario does not yield a corrupted sample. To this extent, it is recommended, to use a discontinuous SCK whenever possible to avoid any potential performance degradation.

$\overline{\text{CS}}$ MODE, 3-WIRE WITHOUT BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host. The connection diagram is shown in Figure 33, and the corresponding timing is given in Figure 34.

With SDI tied to VIO, a rising edge on CNV initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces SDO to high impedance. Once a conversion is initiated, it continues until completion irrespective of the state of CNV. This could be useful, for instance, to bring CNV low to select other SPI devices, such as analog multiplexers; however, CNV must be

returned high before the minimum conversion time elapses and then held high for the maximum possible conversion time to avoid the generation of the busy signal indicator. When the conversion is complete, the AD7693 enters the acquisition phase and powers down. When CNV goes low, the MSB is output onto SDO. The remaining data bits are clocked by subsequent SCK falling edges. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the 16th SCK falling edge or when CNV goes high (whichever occurs first), SDO returns to high impedance.

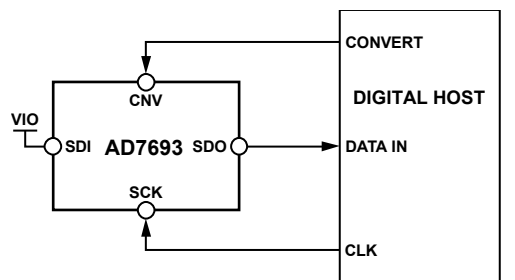


Figure 33. $\overline{\text{CS}}$ Mode, 3-Wire Without Busy Indicator Connection Diagram (SDI High)

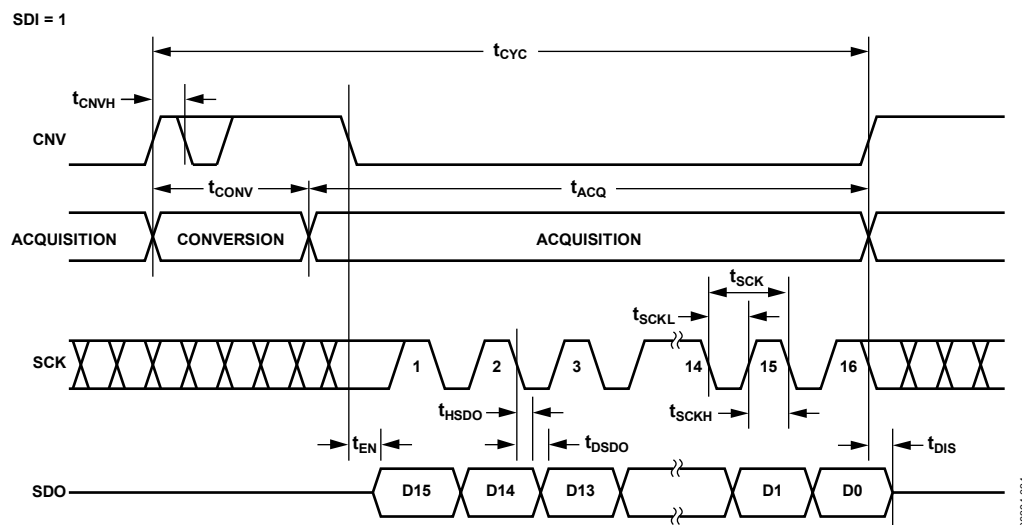


Figure 34. $\overline{\text{CS}}$ Mode, 3-Wire Without Busy Indicator Serial Interface Timing (SDI High)

$\overline{\text{CS}}$ MODE, 3-WIRE WITH BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host having an interrupt input.

The connection diagram is shown in Figure 35, and the corresponding timing is given in Figure 36.

With SDI tied to VIO, a rising edge on CNV initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces SDO to high impedance. SDO is maintained in high impedance until the completion of the conversion irrespective of the state of CNV. Prior to the minimum conversion time, CNV can be used to select other SPI devices, such as analog multiplexers, but CNV must be returned low before the minimum conversion time elapses and then held low for the maximum possible conversion time to guarantee the generation of the busy signal indicator. When the conversion is complete, SDO goes from high

impedance to low impedance. With a pull-up on the SDO line, this transition can be used as an interrupt signal to initiate the data reading controlled by the digital host. The AD7693 then enters the acquisition phase and powers down. The data bits are clocked out, MSB first, by subsequent SCK falling edges. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the optional 17th SCK falling edge or when CNV goes high (whichever occurs first), SDO returns to high impedance.

If multiple AD7693s are selected at the same time, the SDO output pin handles this contention without damage or induced latch-up. Meanwhile, it is recommended to keep this contention as short as possible to limit extra power dissipation.

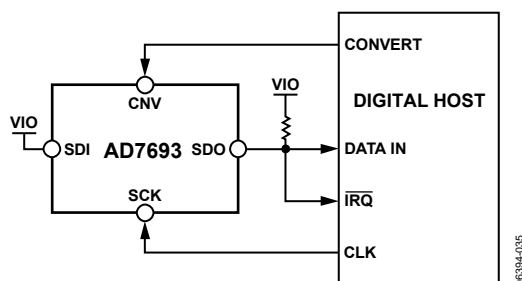


Figure 35. $\overline{\text{CS}}$ Mode, 3-Wire with Busy Indicator Connection Diagram (SDI High)

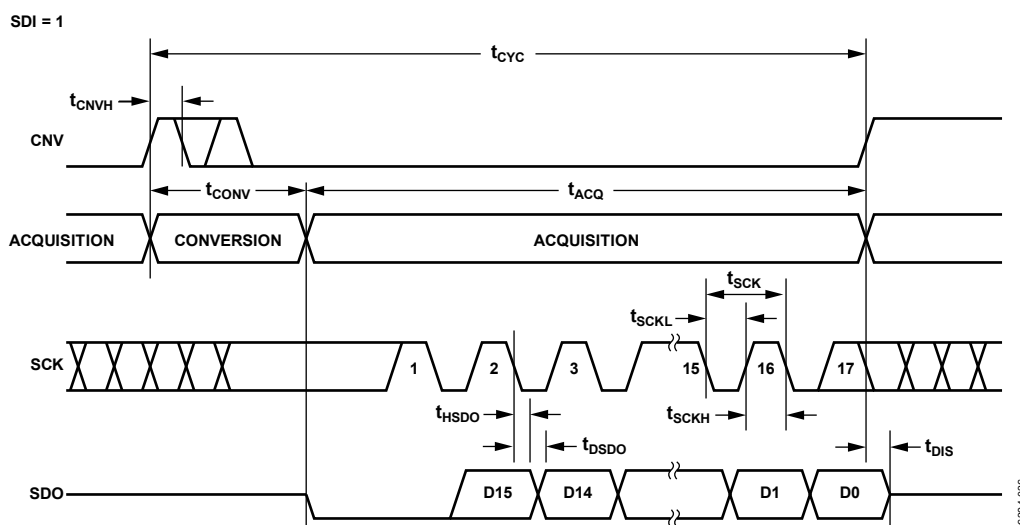


Figure 36. $\overline{\text{CS}}$ Mode, 3-Wire with Busy Indicator Serial Interface Timing (SDI High)

$\overline{\text{CS}}$ MODE, 4-WIRE WITHOUT BUSY INDICATOR

This mode is usually used when multiple AD7693s are connected to an SPI-compatible digital host.

A connection diagram example using two AD7693s is shown in Figure 37, and the corresponding timing is given in Figure 38.

With $\overline{\text{SDI}}$ high, a rising edge on $\overline{\text{CNV}}$ initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces $\overline{\text{SDO}}$ to high impedance. In this mode, $\overline{\text{CNV}}$ must be held high during the conversion phase and the subsequent data readback. (If $\overline{\text{SDI}}$ and $\overline{\text{CNV}}$ are low, $\overline{\text{SDO}}$ is driven low.) Prior to the minimum conversion time, $\overline{\text{SDI}}$ can be used to select other SPI devices, such as analog multiplexers, but $\overline{\text{SDI}}$ must be returned high before the minimum conversion time

elapses and then held high for the maximum possible conversion time to avoid the generation of the busy signal indicator. When the conversion is complete, the AD7693 enters the acquisition phase and powers down. Each ADC result can be read by bringing its $\overline{\text{SDI}}$ input low, which consequently outputs the MSB onto $\overline{\text{SDO}}$. The remaining data bits are clocked by subsequent $\overline{\text{SCK}}$ falling edges. The data is valid on both $\overline{\text{SCK}}$ edges. Although the rising edge can be used to capture the data, a digital host using the $\overline{\text{SCK}}$ falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the 16th $\overline{\text{SCK}}$ falling edge or when $\overline{\text{SDI}}$ goes high (whichever occurs first), $\overline{\text{SDO}}$ returns to high impedance and another AD7693 can be read.

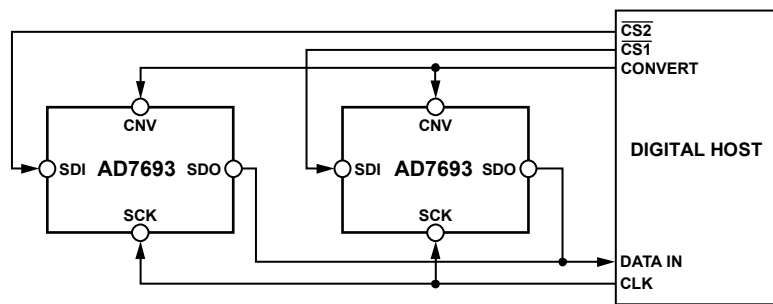


Figure 37. $\overline{\text{CS}}$ Mode, 4-Wire Without Busy Indicator Connection Diagram

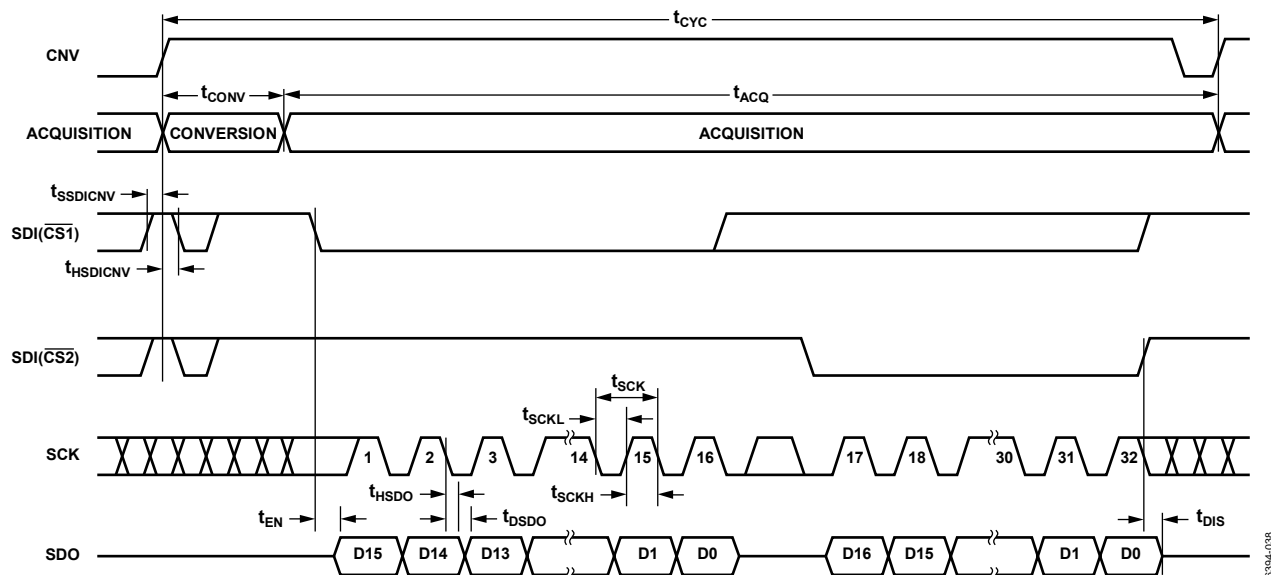


Figure 38. $\overline{\text{CS}}$ Mode, 4-Wire Without Busy Indicator Serial Interface Timing

$\overline{\text{CS}}$ MODE, 4-WIRE WITH BUSY INDICATOR

This mode is usually used when a single AD7693 is connected to an SPI-compatible digital host with an interrupt input and it is desired to keep CNV, which is used to sample the analog input, independent of the signal used to select the data reading. This requirement is particularly important in applications where low jitter on CNV is desired.

The connection diagram is shown in Figure 39, and the corresponding timing is given in Figure 40.

With SDI high, a rising edge on CNV initiates a conversion, selects the $\overline{\text{CS}}$ mode, and forces SDO to high impedance. In this mode, CNV must be held high during the conversion phase and the subsequent data readback. (If SDI and CNV are low, SDO is driven low.) Prior to the minimum conversion time, SDI can be used to select other SPI devices, such as analog multiplexers,

but SDI must be returned low before the minimum conversion time elapses and then held low for the maximum possible conversion time to guarantee the generation of the busy signal indicator. When the conversion is complete, SDO goes from high impedance to low impedance. With a pull-up on the SDO line, this transition can be used as an interrupt signal to initiate the data readback controlled by the digital host. The AD7693 then enters the acquisition phase and powers down. The data bits are clocked out, MSB first, by subsequent SCK falling edges. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate, provided it has an acceptable hold time. After the optional 17th SCK falling edge, or when SDI goes high (whichever occurs first), SDO returns to high impedance.

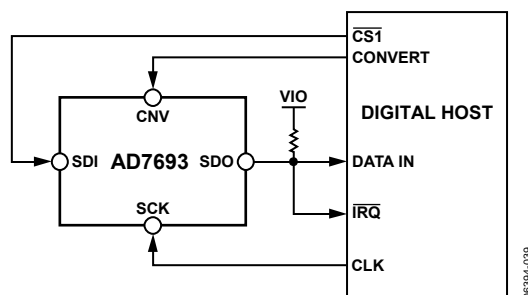


Figure 39. $\overline{\text{CS}}$ Mode, 4-Wire with Busy Indicator Connection Diagram

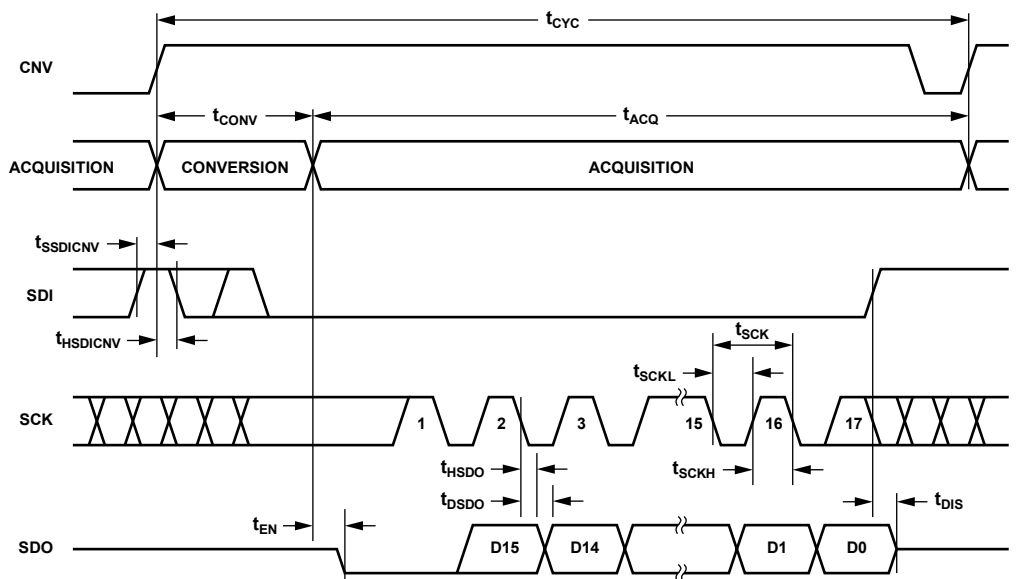


Figure 40. $\overline{\text{CS}}$ Mode, 4-Wire with Busy Indicator Serial Interface Timing

CHAIN MODE WITHOUT BUSY INDICATOR

This mode can be used to daisy-chain multiple AD7693s on a 3-wire serial interface. This feature is useful for reducing component count and wiring connections, for example, in isolated multiconverter applications or for systems with a limited interfacing capacity. Data readback is analogous to clocking a shift register.

A connection diagram example using two AD7693s is shown in Figure 41, and the corresponding timing is given in Figure 42.

When SDI and CNV are low, SDO is driven low. With SCK low, a rising edge on CNV initiates a conversion, selects the chain mode, and disables the busy indicator. In this mode, CNV is held high during the conversion phase and the subsequent data

readback. When the conversion is complete, the MSB is output onto SDO and the AD7693 enters the acquisition phase and powers down. The remaining data bits stored in the internal shift register are clocked by subsequent SCK falling edges. For each ADC, SDI feeds the input of the internal shift register and is clocked by the SCK falling edge. Each ADC in the chain outputs its data MSB first, and $16 \times N$ clocks are required to read back the N ADCs. The data is valid on both SCK edges. Although the rising edge can be used to capture the data, a digital host using the SCK falling edge will allow a faster reading rate and consequently more AD7693s in the chain, provided the digital host has an acceptable hold time. The maximum conversion rate can be reduced due to the total readback time.

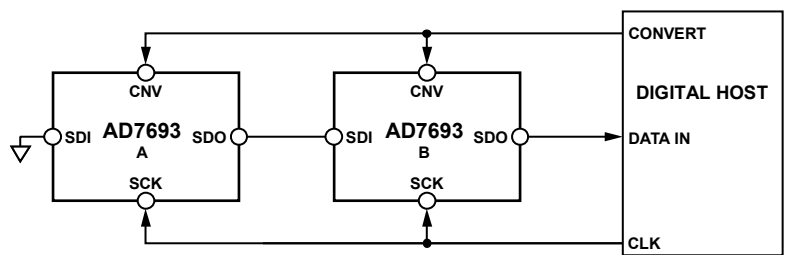


Figure 41. Chain Mode Without Busy Indicator Connection Diagram

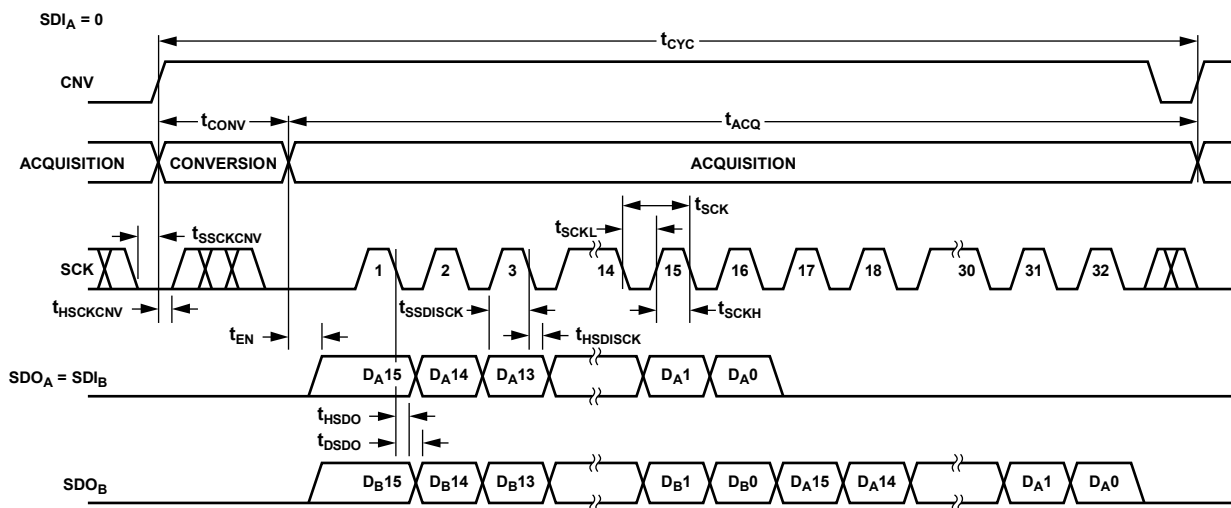
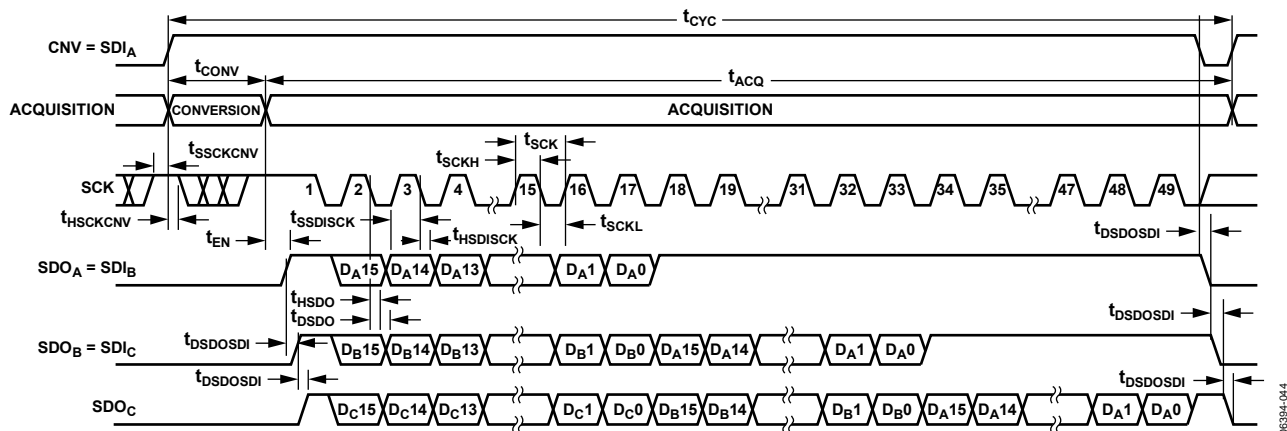


Figure 42. Chain Mode Without Busy Indicator Serial Interface Timing

This mode can also be used to daisy-chain multiple [AD7693s](#) on a 3-wire serial interface while providing a busy indicator. This feature is useful for reducing component count and wiring connections, for example, in isolated multiconverter applications or for systems with a limited interfacing capacity. Data readback is analogous to clocking a shift register.

When SDI and CNV are low, SDO is driven low. With SCK high, a rising edge on CNV initiates a conversion, selects the chain mode, and enables the busy indicator feature. In this mode, CNV is held high during the conversion phase and the subsequent data readback. When all ADCs in the chain have

06394-043



06394-044

APPLICATION HINTS

LAYOUT

The printed circuit board that houses the [AD7693](#) should be designed so that the analog and digital sections are separated and confined to certain areas of the board. The pinout of the [AD7693](#), with all its analog signals on the left side and all its digital signals on the right side, eases this task.

Avoid running digital lines under the device because these couple noise onto the die unless a ground plane under the [AD7693](#) is used as a shield. Fast switching signals, such as CNV or clocks, should not run near analog signal paths. Crossover of digital and analog signals should be avoided.

At least one ground plane should be used. It could be common or split between the digital and analog sections. In the latter case, the planes should be joined underneath the [AD7693](#).

The [AD7693](#) voltage reference input REF has a dynamic input impedance and should be decoupled with minimal parasitic inductances. This is done by placing the reference decoupling ceramic capacitor close to, ideally right up against, the REF and GND pins and connecting them with wide, low impedance traces.

Finally, the power supplies VDD and VIO of the [AD7693](#) should be decoupled with ceramic capacitors, typically 100 nF, placed close to the [AD7693](#) and connected using short, wide traces to provide low impedance paths and reduce the effect of glitches on the power supply lines.

An example of a layout following these rules is shown in Figure 45 and Figure 46.

EVALUATING THE [AD7693](#) PERFORMANCE

Other recommended layouts for the [AD7693](#) are outlined in the documentation of the evaluation board for the [AD7693](#) ([EVAL-AD7693SDZ](#)). The evaluation board package includes a fully assembled and tested evaluation board, documentation, and software for controlling the board from a PC via the [EVAL-SDP-CB1Z](#).

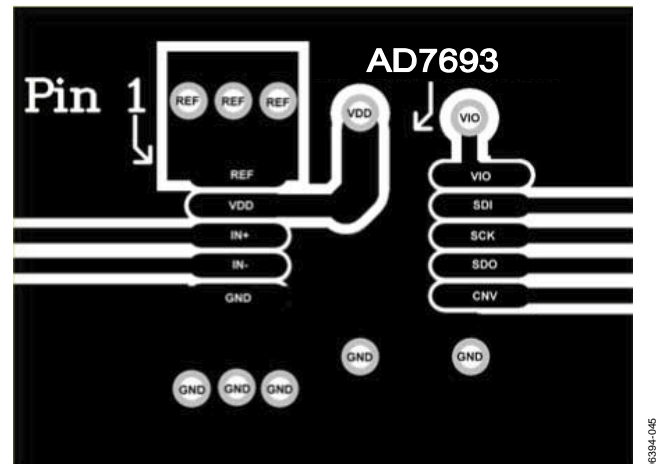


Figure 45. Example Layout of the [AD7693](#) (Top Layer)

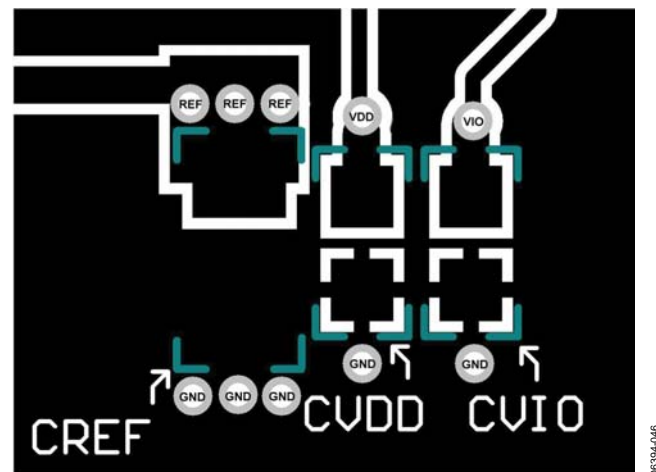
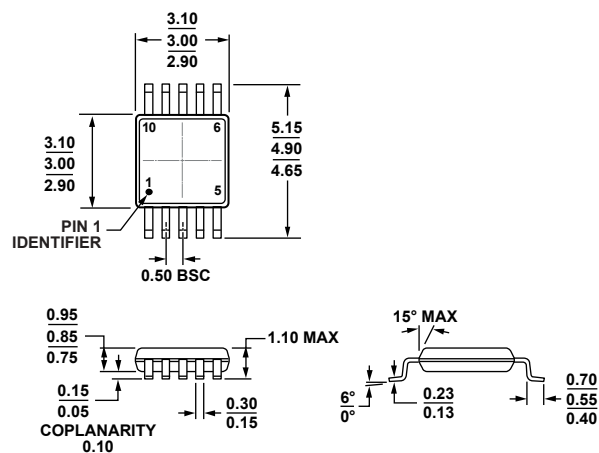


Figure 46. Example Layout of the [AD7693](#) (Bottom Layer)

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-BA

Figure 47.10-Lead Mini Small Outline Package [MSOP]
(RM-10)

Dimensions shown in millimeters

091709-A

ORDERING GUIDE

Model ^{1, 2, 3}	Temperature Range	Package Description	Package Option	Marking Code	Ordering Quantity
AD7693BRMZ	−40°C to +85°C	10-Lead MSOP	RM-10	C4Y	Tube, 50
AD7693BRMZRL7	−40°C to +85°C	10-Lead MSOP	RM-10	C4Y	Reel, 1,000
EVAL-AD7693SDZ		Evaluation Board			
EVAL-SDP-CB1Z		Controller Board			

¹ Z = RoHS Compliant Part.² The EVAL-AD7693SDZ can be used as a standalone evaluation board or in conjunction with the EVAL-SDP-CB1Z for evaluation/demonstration purposes.³ The EVAL-SDP-CB1Z allows a PC to control and communicate with all Analog Devices evaluation boards ending in the SD designator.